onsemi

NPN VHF/UHF Transistor

MMBTH10M3T5G

The MMBTH10M3T5G device is a spin-off of our popular SOT-23 three-leaded device. It is designed for general purpose VHF/UHF applications and is housed in the SOT-723 surface mount package. This device is ideal for low-power surface mount applications where board space is at a premium.

Features

- Reduces Board Space
- This is a Halide–Free Device
- This is a Pb–Free Device

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	25	Vdc
Collector – Base Voltage	V _{CBO}	30	Vdc
Emitter – Base Voltage	V _{EBO}	3.0	Vdc

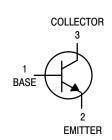
THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Total Device Dissipation FR-5 Board (Note 1) T _A = 25°C Derate above 25°C	PD	265 2.1	m₩ mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	470	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C Derate above 25°C	P _D	640 5.1	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	195	°C/W
Junction and Storage Temperature	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-5 = 1.0 \times 0.75 \times 0.062 in.

2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.



MARKING DIAGRAM



ORDERING INFORMATION

Device	Package	Shipping [†]
MMBTH10M3T5G	SOT-723 (Pb-Free)	8000/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

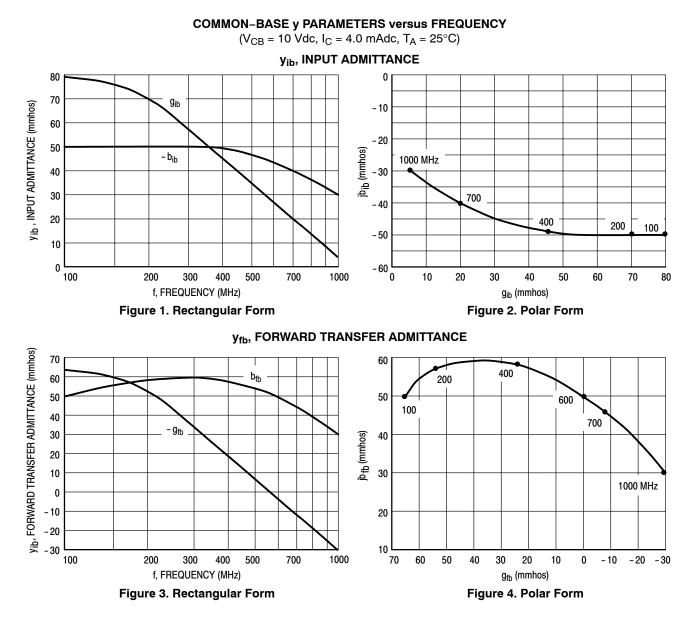
MMBTH10M3T5G

ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	V _{(BR)CEO}	25	_	-	Vdc
Collector–Base Breakdown Voltage $(I_C = 100 \ \mu Adc, I_E = 0)$	V _{(BR)CBO}	30	_	-	Vdc
Emitter–Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$	V _{(BR)EBO}	3.0	_	-	Vdc
Collector Cutoff Current (V _{CB} = 25 Vdc, I _E = 0)	I _{CBO}	-	_	100	nAdc
Emitter Cutoff Current ($V_{EB} = 2.0 \text{ Vdc}, I_C = 0$)	I _{EBO}	-	-	100	nAdc
ON CHARACTERISTICS					
DC Current Gain (I _C = 4.0 mAdc, V _{CE} = 10 Vdc)	h _{FE}	60	_	_	-
Collector–Emitter Saturation Voltage $(I_C = 4.0 \text{ mAdc}, I_B = 0.4 \text{ mAdc})$	V _{CE(sat)}	-	_	0.5	Vdc
Base-Emitter On Voltage (I _C = 4.0 mAdc, V _{CE} = 10 Vdc)	V _{BE}	_	-	0.95	Vdc
SMALL-SIGNAL CHARACTERISTICS				•	
Current–Gain – Bandwidth Product (I _C = 4.0 mAdc, V _{CE} = 10 Vdc, f = 100 MHz)	f _T	650	_	_	MHz
Collector–Base Capacitance $(V_{CB}= 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	C _{cb}	-	_	0.7	pF
Common–Base Feedback Capacitance $(V_{CB}$ = 10 Vdc, I _E = 0, f = 1.0 MHz)	C _{rb}	-	-	0.65	pF
Collector Base Time Constant (I _C = 4.0 mAdc, V_{CB} = 10 Vdc, f = 31.8 MHz)	rb′C _c	-	-	9.0	ps

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TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS

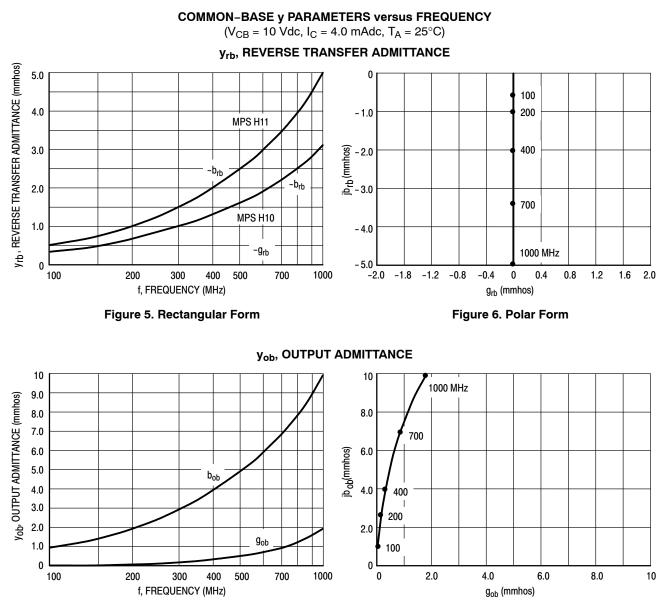


Figure 7. Rectangular Form

Figure 8. Polar Form



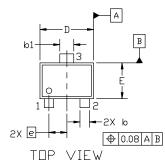


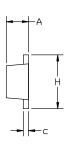
SOT-723 1.20x0.80x0.50, 0.40P CASE 631AA ISSUE E

DATE 24 JAN 2024

NDTES:

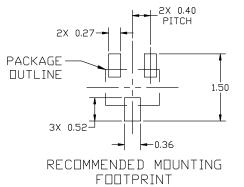
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSION: MILLIMETERS. 1.
- 2.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM З. LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS OR GATE BURRS.



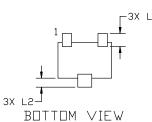


SIDE VIEW

		MILLIMETERS			
	DIM	MIN.	NDM.	MAX.	
1	А	0.45	0.50	0.55	
	b	0.15	0.21	0.27	
	b1	0.25	0.31	0.37	
	С	0.07	0.12	0.17	
	D	1.15	1.20	1.25	
	E	0.75	0.80	0.85	
	e	0.40 BSC			
	Н	1.15	1.20	1.25	
	L	0.29 REF			
	L2	0.15	0.20	0.25	



*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.



GENERIC **MARKING DIAGRAM***



XX = Specific Device Code Μ = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

2. EMITTER 2.	II: STYLE 3: ANODE PIN 1. ANODE N/C 2. ANODE CATHODE 3. CATHODE	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 5: PIN 1. GATE 2. SOURCE 3. DRAIN		
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DESCRIPTION: SOT-723 1.20x0.80x0.50, 0.40P					PAGE 1 OF 1

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